

2.7V Dual Channel 10-Bit A/D Converter with SPI Serial Interface

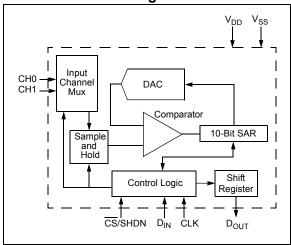
Features

- · 10-bit resolution
- ±1 LSB maximum DNL
- ±1 LSB maximum INL
- Analog inputs programmable as single-ended or pseudo-differential pairs
- · On-chip sample and hold
- SPI serial interface (modes 0,0 and 1,1)
- · Single supply operation: 2.7V 5.5V
- 200 ksps max sampling rate at $V_{\rm DD}$ = 5V
- 75 ksps max sampling rate at V_{DD} = 2.7V
- · Low power CMOS technology:
 - 5 nA typical standby current, 2 μA maximum
 - 550 µA maximum active current at 5V
- Industrial temp range: -40°C to +85°C
- 8-pin MSOP, PDIP, SOIC and TSSOP packages

Applications

- · Sensor Interface
- · Process Control
- · Data Acquisition
- · Battery Operated Systems

Functional Block Diagram

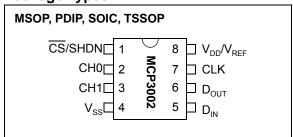


Description

The Microchip Technology Inc. MCP3002 is a successive approximation 10-bit Analog-to-Digital (A/D) Converter with on-board sample and hold circuitry. The MCP3002 is programmable to provide a single pseudo-differential input pair or dual single-ended inputs. Differential Nonlinearity (DNL) and Integral Nonlinearity (INL) are both specified at ±1 LSB. Communication with the device is done using a simple serial interface compatible with the SPI protocol. The device is capable of conversion rates of up to 200 ksps at 5V and 75 ksps at 2.7V. The MCP3002 device operates over a broad voltage range (2.7V - 5.5V). Low-current design permits operation with a typical standby current of 5 nA and a typical active current of 375 µA.

The MCP3002 is offered in 8-pin MSOP, PDIP, TSSOP and 150 mil SOIC packages.

Package Types



NOTES:

1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

V _{DD}	7.0V
All Inputs and Outputs w.r.t. V _{SS}	0.6V to V _{DD} + 0.6V
Storage Temperature	65°C to +150°C
Ambient temperature with power applied	–65°C to +150°C
ESD Protection On All Pins (HBM)	≥ 4 kV

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

			se noted.			
PARAMETER	SYM	MIN	TYP	MAX	UNITS	CONDITIONS
Conversion Rate:						
Conversion Time	T _{CONV}	_	_	10	clock cycles	
Analog Input Sample Time	T _{SAMPLE}		1.5		clock cycles	
Throughput Rate	F _{SAMPLE}	_	_	200 75	ksps ksps	V _{DD} = 5V V _{DD} = 2.7V
DC Accuracy:						
Resolution			10		bits	
Integral Nonlinearity	INL	_	±0.5	±1	LSB	
Differential Nonlinearity	DNL	_	±0.25	±1	LSB	No missing codes over temperature
Offset Error		_	_	±1.5	LSB	
Gain Error		_	_	±1	LSB	
Dynamic Performance:						
Total Harmonic Distortion	THD	_	-76		dB	V _{IN} = 0.1V to 4.9V@1 kHz
Signal to Noise and Distortion (SINAD)	SINAD	_	61	1	dB	V _{IN} = 0.1V to 4.9V@1 kHz
Spurious Free Dynamic Range	SFDR	_	78	_	dB	V _{IN} = 0.1V to 4.9V@1 kHz
Analog Inputs:						
Input Voltage Range for CH0 or CH1 in Single-Ended Mode		V _{SS}	_	V_{DD}	V	
Input Voltage Range for IN+ In pseudo-differential Mode	IN+	IN-	_	V _{DD} +IN-		
Input Voltage Range for IN- In pseudo-differential Mode	IN-	V _{SS} -100	_	V _{SS} +100	mV	
Leakage Current		_	0.001	±1	μΑ	
Switch Resistance	R _{SS}	_	1K	_	Ω	See Figure 4-1
Sample Capacitor	C _{SAMPLE}	_	20	_	pF	See Figure 4-1

Note 1: This parameter is established by characterization and not 100% tested.

^{2:} The sample cap will eventually lose charge, especially at elevated temperatures, therefore f_{CLK} ≥10 kHz for temperatures at or above 70°C.

ELECTRICAL CHARACTERISTICS (CONTINUED)

All parameters apply at V_{DD} = 5V, T_A = -40°C to +85°C, f_{SAMPLE} = 200 ksps and f_{CLK} = 16* f_{SAMPLE} , unless otherwise noted. Typical values apply for V_{DD} = 5V, T_A = +25°C, unless otherwise noted.

PARAMETER	SYM	MIN	TYP	MAX	UNITS	CONDITIONS
Digital Input/Output:		<u> </u>				
Data Coding Format		St	raight Bin	ary		
High Level Input Voltage	V _{IH}	0.7 V _{DD}	_	_	V	
Low Level Input Voltage	V _{IL}	_	_	0.3 V _{DD}	V	
High Level Output Voltage	V _{OH}	4.1	_	_	V	I _{OH} = -1 mA, V _{DD} = 4.5V
Low Level Output Voltage	V _{OL}	_	_	0.4	V	$I_{OL} = 1 \text{ mA}, V_{DD} = 4.5 \text{V}$
Input Leakage Current	I _{LI}	-10	_	10	μΑ	$V_{IN} = V_{SS}$ or V_{DD}
Output Leakage Current	I _{LO}	-10	_	10	μΑ	$V_{OUT} = V_{SS}$ or V_{DD}
Pin Capacitance (All Inputs/Outputs)	C _{IN} , C _{OUT}	_	_	10	pF	V _{DD} = 5.0V (Note 1) T _A = 25°C, f = 1 MHz
Timing Parameters:	!	!				-
Clock Frequency	f _{CLK}	_	_	3.2 1.2	MHz MHz	V _{DD} = 5V (Note 2) V _{DD} = 2.7V (Note 2)
Clock High Time	t _{HI}	140	_	_	ns	
Clock Low Time	t _{LO}	140	_	_	ns	
CS Fall To First Rising CLK Edge	t _{SUCS}	100	_	_	ns	
Data Input Setup Time	t _{SU}	50	_	_	ns	
Data Input Hold Time	t _{HD}	50	_	_	ns	
CLK Fall To Output Data Valid	t _{DO}	_	_	125 200	ns ns	V_{DD} = 5V, see Figure 1-2 V_{DD} = 2.7V, see Figure 1-2
CLK Fall To Output Enable	t _{EN}	_	_	125 200	ns ns	V_{DD} = 5V, see Figure 1-2 V_{DD} = 2.7V, see Figure 1-2
CS Rise To Output Disable	tDIS	_	_	100	ns	See Test Circuits, Figure 1-2 Note 1
CS Disable Time	t _{CSH}	310	_	_	ns	
D _{OUT} Rise Time	t _R	_	_	100	ns	See Test Circuits, Figure 1-2 Note 1
D _{OUT} Fall Time	t _F	_	_	100	ns	See Test Circuits, Figure 1-2 Note 1
Power Requirements:	1					•
Operating Voltage	V_{DD}	2.7	_	5.5	V	
Operating Current	I _{DD}	_	525 300	650 —	μΑ	V_{DD} = 5.0V, D_{OUT} unloaded V_{DD} = 2.7V, D_{OUT} unloaded
Standby Current	I _{DDS}	_	0.005	2	μA	CS = V _{DD} = 5.0V

Note 1: This parameter is established by characterization and not 100% tested.

^{2:} The sample cap will eventually lose charge, especially at elevated temperatures, therefore f_{CLK} ≥10 kHz for temperatures at or above 70°C.

TEMPERATURE CHARACTERISTICS

Electrical Specifications: Unless otherwise indicated, V_{DD} = +2.7V to +5.5V, V_{SS} = GND.								
Parameters	Sym	Min	Тур	Max	Units	Conditions		
Temperature Ranges								
Specified Temperature Range	T _A	-40	_	+85	°C			
Operating Temperature Range	T _A	-40	_	+85	°C			
Storage Temperature Range	T _A	-65	_	+150	°C			
Thermal Package Resistances								
Thermal Resistance, 8L-MSOP	θ_{JA}	_	211	_	°C/W			
Thermal Resistance, 8L-PDIP	θ_{JA}	_	89.5	_	°C/W			
Thermal Resistance, 8L-SOIC	θ_{JA}	_	149.5	_	°C/W			
Thermal Resistance, 8L-TSSOP	θ_{JA}	_	139	_	°C/W			

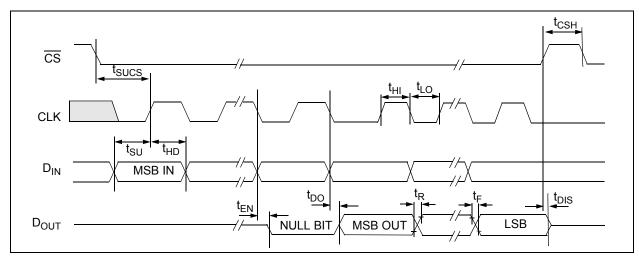


FIGURE 1-1: Serial Timing.

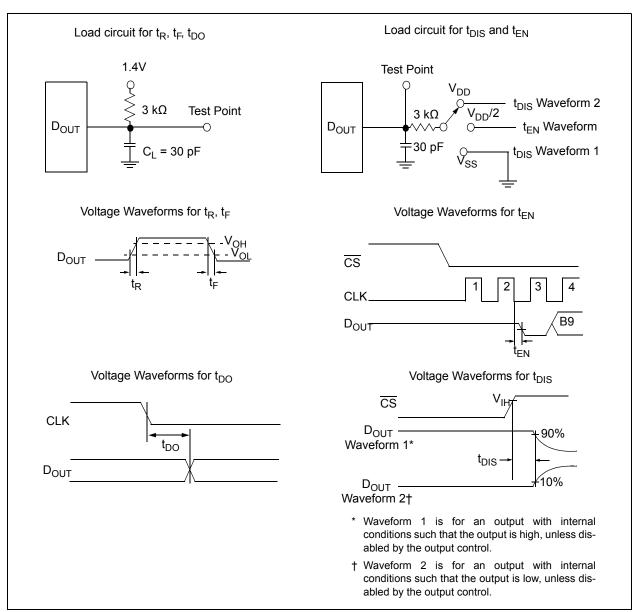


FIGURE 1-2: Test Circuits.

2.0 TYPICAL PERFORMANCE CHARACTERISTICS

Note: The graphs provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

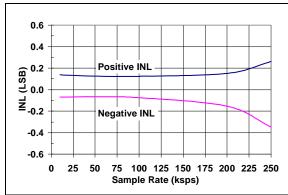


FIGURE 2-1: Integral Nonlinearity (INL) vs. Sample Rate.

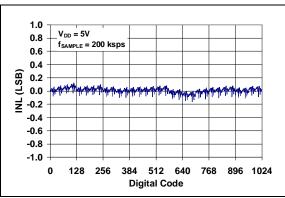


FIGURE 2-2: Integral Nonlinearity (INL) vs. Code.

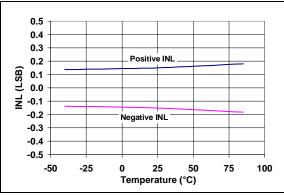


FIGURE 2-3: Integral Nonlinearity (INL) vs. Temperature.

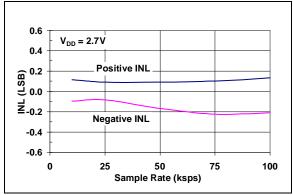


FIGURE 2-4: Integral Nonlinearity (INL) vs. Sample Rate $(V_{DD} = 2.7V)$.

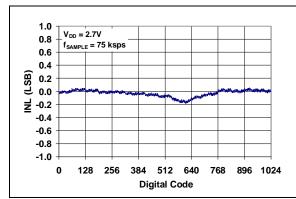


FIGURE 2-5: Integral Nonlinearity (INL) vs. Code ($V_{DD} = 2.7V$).

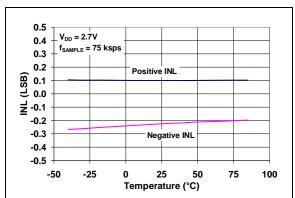


FIGURE 2-6: Integral Nonlinearity (INL) vs. Temperature ($V_{DD} = 2.7V$).

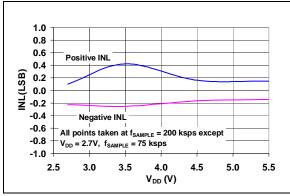


FIGURE 2-7: Integral Nonlinearity (INL) vs. $V_{DD.}$

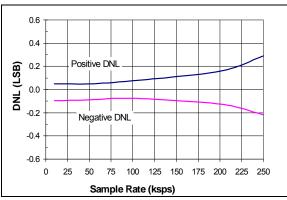


FIGURE 2-8: Differential Nonlinearity (DNL) vs. Sample Rate.

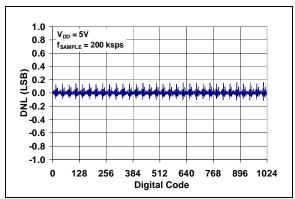


FIGURE 2-9: Differential Nonlinearity (DNL) vs. Code (Representative Part).

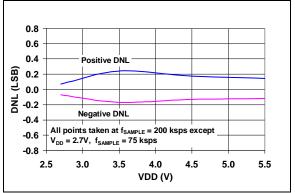


FIGURE 2-10: Differential Nonlinearity (DNL) vs. V_{DD}

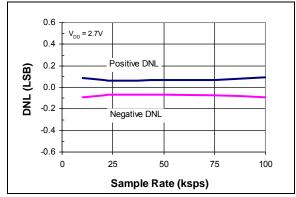


FIGURE 2-11: Differential Nonlinearity (DNL) vs. Sample Rate ($V_{DD} = 2.7V$).

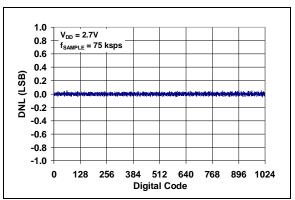


FIGURE 2-12: Differential Nonlinearity (DNL) vs. Code (Representative Part, $V_{DD} = 2.7V$).

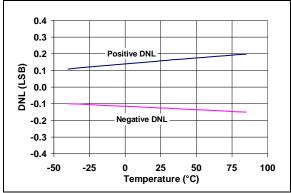


FIGURE 2-13: Differential Nonlinearity (DNL) vs. Temperature.

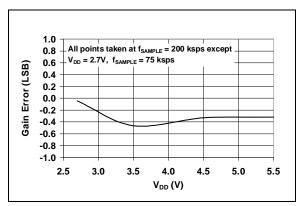


FIGURE 2-14: Gain Error vs. V_{DD} .

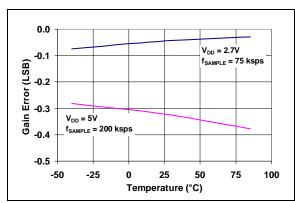


FIGURE 2-15: Gain Error vs. Temperature.

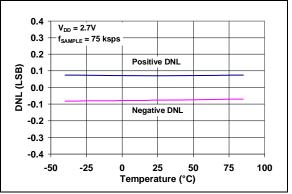


FIGURE 2-16: Differential Nonlinearity (DNL) vs. Temperature ($V_{DD} = 2.7V$).

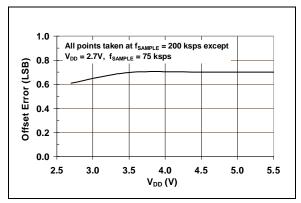


FIGURE 2-17: Offset Error vs. V_{DD}.

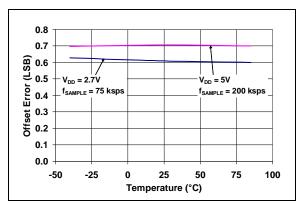


FIGURE 2-18: Offset Error vs. Temperature.

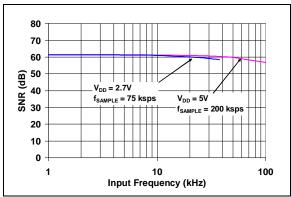


FIGURE 2-19: Signal-to-Noise Ratio (SNR) vs. Input Frequency.

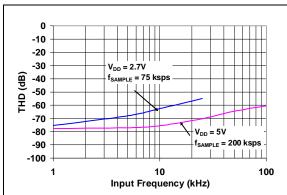


FIGURE 2-20: Total Harmonic Distortion (THD) vs. Input Frequency.

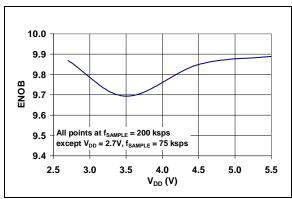


FIGURE 2-21: Effective Number of Bits (ENOB) vs. V_{DD} .

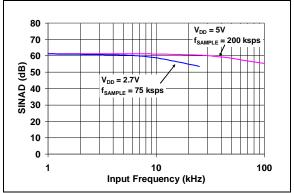


FIGURE 2-22: Signal-to-Noise and Distortion (SINAD) vs. Input Frequency.

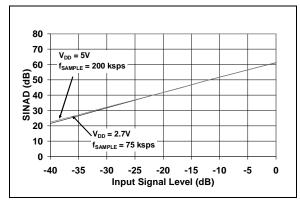


FIGURE 2-23: Signal-to-Noise and Distortion (SINAD) vs. Signal Level.

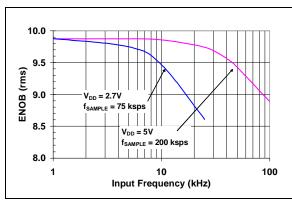


FIGURE 2-24: Effective Number of Bits (ENOB) vs. Input Frequency.

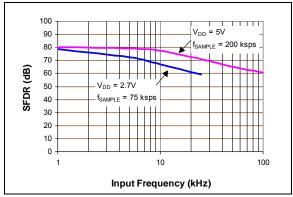


FIGURE 2-25: Spurious Free Dynamic Range (SFDR) vs. Input Frequency.

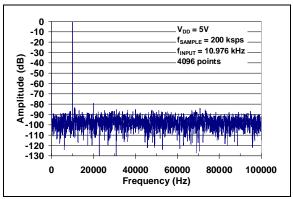


FIGURE 2-26: Frequency Spectrum of 10 kHz input (Representative Part).

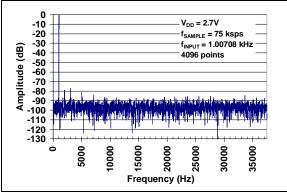


FIGURE 2-27: Frequency Spectrum of 1 kHz input (Representative Part, $V_{DD} = 2.7V$).

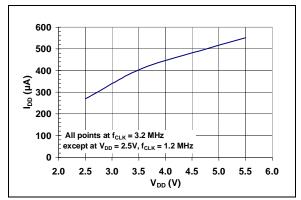


FIGURE 2-28: I_{DD} vs. V_{DD} .

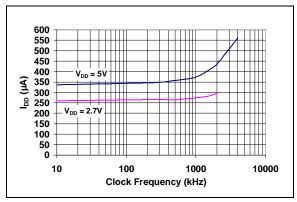


FIGURE 2-29: I_{DD} vs. Clock Frequency.

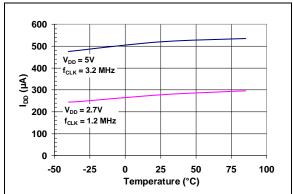


FIGURE 2-30: I_{DD} vs. Temperature.

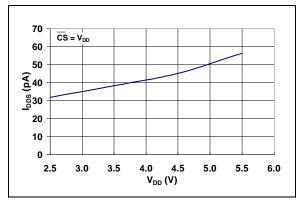


FIGURE 2-31: I_{DDS} vs. V_{DD} .

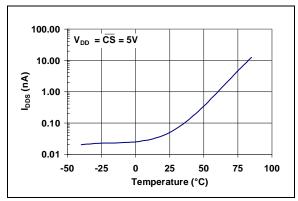


FIGURE 2-32: I_{DDS} vs. Temperature.

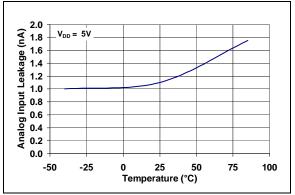


FIGURE 2-33: Analog Input leakage current vs. Temperature.

3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1. Additional descriptions of the device pins follows.

TABLE 3-1: PIN FUNCTION TABLE

MCP3002					
MSOP, PDIP, SOIC, TSSOP	Symbol	Description			
1	CS/SHDN	Chip Select/Shutdown Input			
2	CH0	Channel 0 Analog Input			
3	CH1	Channel 1 Analog Input			
4	V_{SS}	Ground			
5	D _{IN}	Serial Data In			
6	D _{OUT}	Serial Data Out			
7	CLK	Serial Clock			
8	V_{DD}/V_{REF}	+2.7V to 5.5V Power Supply and Reference Voltage Input			

3.1 Analog Inputs (CH0/CH1)

Analog inputs for channels 0 and 1 respectively. These channels can programmed to be used as two independent channels in single ended-mode or as a single pseudo-differential input where one channel is IN+ and one channel is IN-. See **Section 5.0 "Serial Communications"** for information on programming the channel configuration.

3.2 Chip Select/Shutdown (CS/SHDN)

The $\overline{\text{CS}}/\text{SHDN}$ pin is used to initiate communication with the device when pulled low and will end a conversion and put the <u>device</u> in low power standby when pulled high. The $\overline{\text{CS}}/\text{SHDN}$ pin must be pulled high between conversions.

3.3 Serial Clock (CLK)

The SPI clock pin is used to initiate a conversion and to clock out each bit of the conversion as it takes place. See Section 6.2 "Maintaining Minimum Clock Speed" for constraints on clock speed.

3.4 Serial Data Input (D_{IN})

The SPI port serial data input pin is used to clock in input channel configuration data.

3.5 Serial Data Output (DOUT)

The SPI serial data output pin is used to shift out the results of the A/D conversion. Data will always change on the falling edge of each clock as the conversion takes place.

NOTES:

4.0 DEVICE OPERATION

The MCP3002 A/D converter employs a conventional SAR architecture. With this architecture, a sample is acquired on an internal sample/hold capacitor for 1.5 clock cycles starting on the second rising edge of the serial clock after the start bit has been received. Following this sample time, the input switch of the converter opens and the device uses the collected charge on the internal sample and hold capacitor to produce a serial 10-bit digital output code. Conversion rates of 200 ksps are possible on the MCP3002. See Section 6.2 "Maintaining Minimum Clock Speed" for information on minimum clock rates. Communication with the device is done using a 3-wire SPI compatible interface.

4.1 Analog Inputs

The MCP3002 device offers the choice of using the analog input channels configured as two single-ended inputs that are referenced to V_{SS} or a single pseudo-differential input. The configuration setup is done as part of the serial command before each conversion begins. When used in the psuedo-differential mode, CH0 and CH1 are programmed as the IN+ and IN- inputs as part of the command string transmitted to the device. The IN+ input can range from IN- to the reference voltage, V_{DD} . The IN- input is limited to ± 100 mV from the V_{SS} rail. The IN- input can be used to cancel small signal common-mode noise which is present on both the IN+ and IN- inputs.

For the A/D converter to meet specification, the charge holding capacitor (C_{SAMPLE}) must be given enough time to acquire a 10-bit accurate voltage level during the 1.5 clock cycle sampling period. The analog input model is shown in Figure 4-1.

In this diagram, it is shown that the source impedance (R_S) adds to the internal sampling switch (R_{SS}) impedance, directly affecting the time that is required to charge the capacitor, C_{SAMPLE} . Consequently, larger source impedances increase the offset, gain, and integral linearity errors of the conversion.

Ideally, the impedance of the signal source should be near zero. This is achievable with an operational amplifier such as the MCP601 which has a closed loop output impedance of tens of ohms. The adverse affects of higher source impedances are shown in Figure 4-2.

When operating in the pseudo-differential mode, if the voltage level of IN+ is equal to or less than IN-, the resultant code will be 000h. If the voltage at IN+ is equal to or greater than $\{[V_{DD}+(IN-)]-1\,LSB\}$, then the output code will be 3FFh. If the voltage level at IN- is more than 1 LSB below V_{SS} , then the voltage level at the IN+ input will have to go below V_{SS} to see the 000h output code. Conversely, if IN- is more than 1 LSB above V_{SS} , then the 3FFh code will not be seen unless the IN+ input level goes above V_{DD} level. If the voltage at IN+ is equal to or greater than $\{[V_{DD}+(IN-)]-1\,LSB\}$, then the output code will be 3FFh.

4.2 Digital Output Code

The digital output code produced by an A/D Converter is a function of the input signal and the reference voltage. For the MCP3002, V_{DD} is used as the reference voltage.

$$LSB Size = \frac{V_{REF}}{1024}$$

As the V_{DD} level is reduced, the LSB size is reduced accordingly. The theoretical digital output code produced by the A/D Converter is shown below.

Digital Output Code =
$$\frac{1024 \times V_{IN}}{V_{DD}}$$

Where:

 V_{IN} = analog input voltage

 V_{DD} = supply voltage

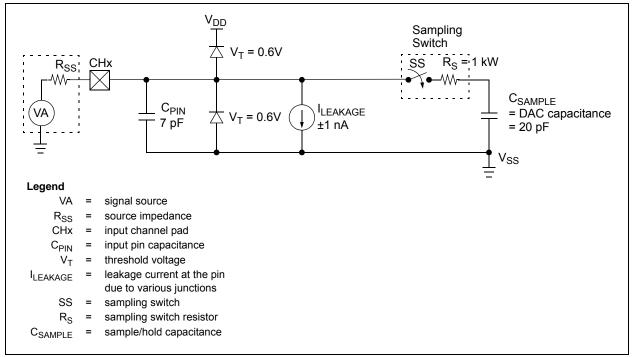


FIGURE 4-1: Analog Input Model.

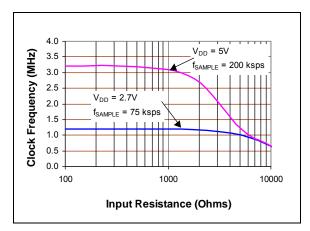


FIGURE 4-2: Maximum Clock Frequency vs. Input resistance (R_S) to maintain less than a 0.1 LSB deviation in INL from nominal conditions.

5.0 SERIAL COMMUNICATIONS

5.1 Overview

Communication with the MCP3002 is done using a standard SPI-compatible serial interface. Initiating communication with the device is done by bringing the CS line low. See Figure 5-1. If the device was powered up with the CS pin low, it must be brought high and back low to initiate communication. The first clock received with CS low and DIN high will constitute a start bit. The SGL/DIFF bit and the ODD/SIGN bit follow the start bit and are used to select the input channel configuration. The SGL/DIFF is used to select single ended or psuedo-differential mode. The ODD/SIGN bit selects which channel is used in single ended mode. and is used to determine polarity in psuedo-differential mode. Following the ODD/SIGN bit, the MSBF bit is transmitted to and is used to enable the LSB first format for the device. If the MSBF bit is high, then the data will come from the device in MSB first format and any further clocks with $\overline{\text{CS}}$ low, will cause the device to output zeros. If the MSBF bit is low, then the device will output the converted word LSB first after the word has been transmitted in the MSB first format. Table 5-1 shows the configuration bits for the MCP3002. The device will begin to sample the analog input on the second rising edge of the clock, after the start bit has been received. The sample period will end on the falling edge of the third clock following the start bit.

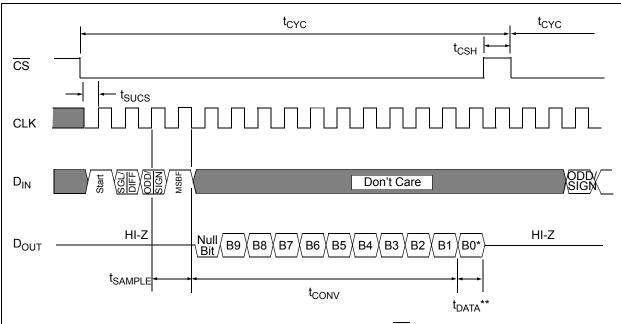
On the falling edge of the clock for the MSBF bit, the device will output a low null bit. The next sequential 10 clocks will output the result of the conversion with MSB first as shown in Figure 5-1. Data is always output from the device on the falling edge of the clock. If all 10 data bits have been transmitted and the device continues to receive clocks while the $\overline{\text{CS}}$ is held low (and the MSBF bit is high), the device will output the conversion result LSB first as shown in Figure 5-2. If more clocks are provided to the device while $\overline{\text{CS}}$ is still low (after the LSB first data has been transmitted), the device will clock out zeros indefinitely.

If necessary, it is possible to bring \overline{CS} low and clock in leading zeros on the D $_{IN}$ line before the start bit. This is often done when dealing with microcontroller-based SPI ports that must send 8 bits at a time. Refer to Section 6.1 "Using the MCP3002 with Microcontroller (MCU) SPI Ports" for more details on using the MCP3002 devices with hardware SPI ports.

If it is desired, the $\overline{\text{CS}}$ can be raised to end the conversion period at any time during the transmission. Faster conversion rates can be obtained by using this technique if not all the bits are captured before starting a new cycle. Some system designers use this method by capturing only the highest-order 8 bits and 'throwing away' the lower 2 bits.

TABLE 5-1: CONFIGURING BITS FOR THE MCP3002

	CONFI	G BITS	CHAI SELEC		CND
	SGL/ ODD/ DIFF SIGN		0	1	GND
Single-Ended	1	0	+		_
Mode 1		1		+	_
Pseudo-	0	0	IN+	IN-	_
Differential Mode	0	1	IN-	IN+	



 $^{^{\}star}$ After completing the data transfer, if further clocks are applied with $\overline{\text{CS}}$ low, the A/D Converter will output zeros indefinitely. See Figure 5-2 for details on obtaining LSB first data.

FIGURE 5-1: Communication with the MCP3002 using MSB first format only.

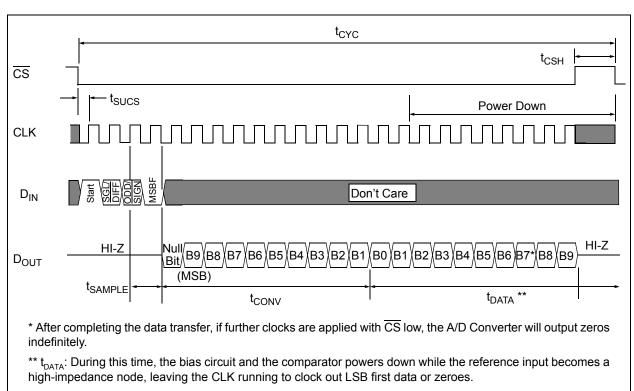


FIGURE 5-2: Communication with MCP3002 using LSB first format.

 $^{^{**}}$ t_{DATA} : during this time, the bias current and the comparator powers down while the reference input becomes a high-impedance node.

6.0 APPLICATIONS INFORMATION

6.1 Using the MCP3002 with Microcontroller (MCU) SPI Ports

With most microcontroller SPI ports, it is required to send groups of eight bits. It is also required that the microcontroller SPI port be configured to clock out data on the falling edge of clock and latch data in on the rising edge. Depending on how communication routines are used, it is very possible that the number of clocks required for communication will not be a multiple of eight. Therefore, it may be necessary for the MCU to send more clocks than are actually required. This is usually done by sending 'leading zeros' before the start bit, which are ignored by the device. As an example, Figure 6-1 and Figure 6-2 show how the MCP3002 can be interfaced to a MCU with a hardware SPI port. Figure 6-1 depicts the operation shown in SPI Mode 0,0, which requires that the SCLK from the MCU idles in the 'low' state, while Figure 6-2 shows the similar case of SPI Mode 1,1 where the clock idles in the 'high' state.

As shown in Figure 6-1, the first byte transmitted to the A/D Converter contains one leading zero before the start bit. Arranging the leading zero this way produces the output 10 bits to fall in positions easily manipulated by the MCU. When the first 8 bits are transmitted to the device, the MSB data bit is clocked out of the A/D Converter on the falling edge of clock number 6. After the second eight clocks have been sent to the device, the receive register will contain the lowest-order eight bits of the conversion results. Easier manipulation of the converted data can be obtained by using this method.

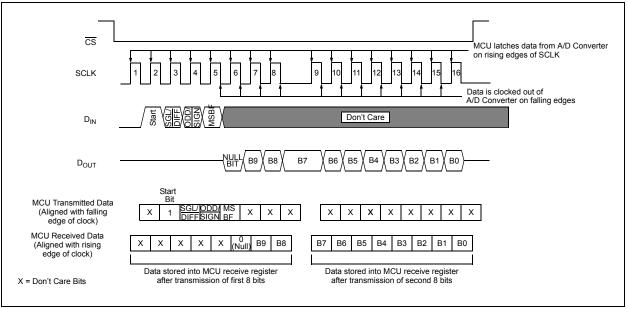


FIGURE 6-1: SPI Communication with the MCP3002 using 8-bit segments (Mode 0,0: SCLK idles low).

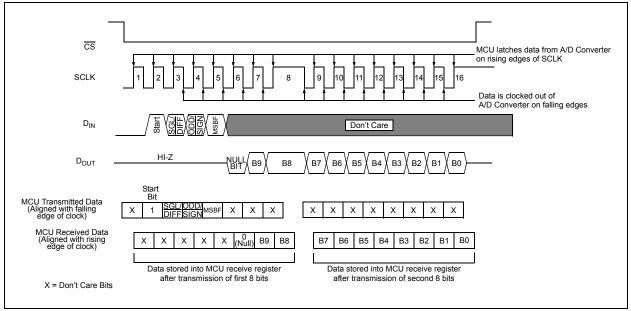


FIGURE 6-2: SPI Communication with the MCP3002 using 8-bit segments (Mode 1,1: SCLK idles high).

6.2 Maintaining Minimum Clock Speed

When the MCP3002 initiates the sample period, charge is stored on the sample capacitor. When the sample period is complete, the device converts one bit for each clock that is received. It is important for the user to note that a slow clock rate will allow charge to bleed off the sample cap while the conversion is taking place. At 85°C (worst case condition), the part will maintain proper charge on the sample cap for 700 μs at V_{DD} = 2.7V and 1.5 ms at V_{DD} = 5V. This means that at V_{DD} = 2.7V, the time it takes to transmit the 1.5 clocks for the sample period and the 10 clocks for the actual conversion must not exceed 700 μs . Failure to meet this criteria may induce linearity errors into the conversion outside the rated specifications.

6.3 Buffering/Filtering the Analog Inputs

If the signal source for the A/D Converter is not a low impedance source, it will have to be buffered or inaccurate conversion results may occur. It is also recommended that a filter be used to eliminate any signals that may be aliased back in to the conversion results. This is illustrated in Figure 6-3 below where an op amp is used to drive, filter, and gain the analog input of the MCP3002. This amplifier provides a low impedance output for the converter input and a low-pass filter, which eliminates unwanted high-frequency noise.

Low-pass (anti-aliasing) filters can be designed using Microchip's interactive FilterLab[®] software. FilterLab will calculate capacitor and resistors values, as well as, determine the number of poles that are required for the application. For more information on filtering signals, see the application note AN699 "Anti-Aliasing Analog Filters for Data Acquisition Systems."

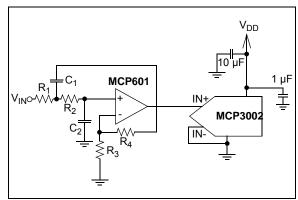


FIGURE 6-3: Typical Anti-Aliasing Filter Circuit (2 pole Active Filter).

6.4 Layout Considerations

When laying out a printed circuit board for use with analog components, care should be taken to reduce noise wherever possible. A bypass capacitor should always be used with this device and should be placed as close as possible to the device pin. A bypass capacitor value of 1 μF is recommended.

Digital and analog traces should be separated as much as possible on the board and no traces should run underneath the device or the bypass capacitor. Extra precautions should be taken to keep traces with high-frequency signals (such as clock lines) as far as possible from analog traces.

Use of an analog ground plane is recommended in order to keep the ground potential the same for all devices on the board. Providing V_{DD} connections to devices in a "star" configuration can also reduce noise by eliminating current return paths and associated errors. See Figure 6-4. For more information on layout tips when using A/D converters, refer to AN-688 "Layout Tips for 12-Bit A/D Converter Applications".

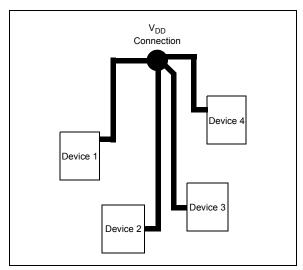


FIGURE 6-4: V_{DD} traces arranged in a 'Star' configuration in order to reduce errors caused by current return paths.

NOTES:

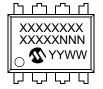
7.0 PACKAGING INFORMATION

7.1 Package Marking Information

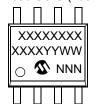




8-Lead PDIP (300 mil)



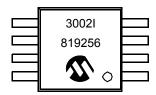
8-Lead SOIC (150 mil)



8-Lead TSSOP



Example:



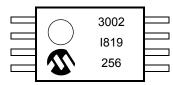
Example:



Example:



Example:



Legend: XX...X Customer-specific information

Y Year code (last digit of calendar year)
YY Year code (last 2 digits of calendar year)
WW Week code (week of January 1 is week '01')

NNN Alphanumeric traceability code

(e3) Pb-free JEDEC designator for Matte Tin (Sn)

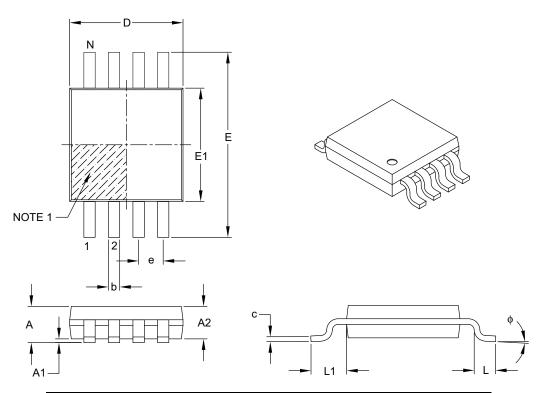
This package is Pb-free. The Pb-free JEDEC designator (e3)

can be found on the outer packaging for this package.

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

8-Lead Plastic Micro Small Outline Package (MS) [MSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units		MILLIMETERS		
Dimension	Dimension Limits		NOM	MAX	
Number of Pins	N		8		
Pitch	е		0.65 BSC		
Overall Height	Α	_	_	1.10	
Molded Package Thickness	A2	0.75	0.85	0.95	
Standoff	A1	0.00	_	0.15	
Overall Width	Е	4.90 BSC			
Molded Package Width	E1		3.00 BSC		
Overall Length	D		3.00 BSC		
Foot Length	L	0.40	0.60	0.80	
Footprint	L1	0.95 REF			
Foot Angle	ф	0°	_	8°	
Lead Thickness	С	0.08	_	0.23	
Lead Width	b	0.22	_	0.40	

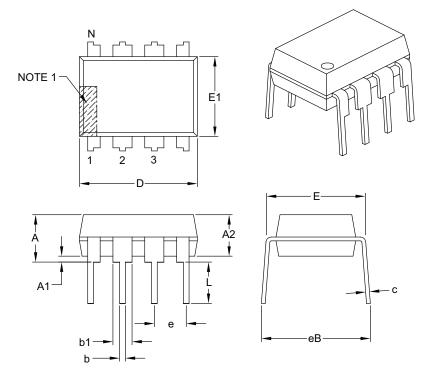
Notes

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- $2. \ \ Dimensions \ D \ and \ E1 \ do \ not \ include \ mold \ flash \ or \ protrusions. \ Mold \ flash \ or \ protrusions \ shall \ not \ exceed \ 0.15 \ mm \ per \ side.$
- 3. Dimensioning and tolerancing per ASME Y14.5M.
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.
 - REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-111B

8-Lead Plastic Dual In-Line (P) - 300 mil Body [PDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units		INCHES		
	Dimension Limits	MIN	NOM	MAX	
Number of Pins	N		8		
Pitch	е		.100 BSC		
Top to Seating Plane	A	_	_	.210	
Molded Package Thickness	A2	.115	.130	.195	
Base to Seating Plane	A1	.015	_	-	
Shoulder to Shoulder Width	E	.290	.310	.325	
Molded Package Width	E1	.240	.250	.280	
Overall Length	D	.348	.365	.400	
Tip to Seating Plane	L	.115	.130	.150	
Lead Thickness	С	.008	.010	.015	
Upper Lead Width	b1	.040	.060	.070	
Lower Lead Width	b	.014	.018	.022	
Overall Row Spacing §	eB	_	_	.430	

Notes:

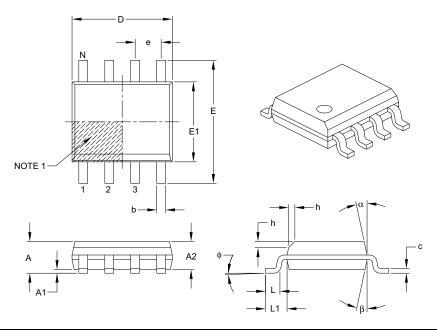
- 1. Pin 1 visual index feature may vary, but must be located with the hatched area.
- 2. § Significant Characteristic.
- 3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
- 4. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-018B

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	MILLIMETERS		
Di	mension Limits	MIN	NOM	MAX
Number of Pins	N		8	
Pitch	е		1.27 BSC	
Overall Height	Α	-	-	1.75
Molded Package Thickness	A2	1.25	_	1
Standoff §	A1	0.10	_	0.25
Overall Width	E	6.00 BSC		
Molded Package Width	E1	3.90 BSC		
Overall Length	D		4.90 BSC	
Chamfer (optional)	h	0.25	_	0.50
Foot Length	L	0.40	_	1.27
Footprint	L1		1.04 REF	
Foot Angle	ф	0°	_	8°
Lead Thickness	С	0.17 – 0.25		
Lead Width	b	0.31	_	0.51
Mold Draft Angle Top	α	5°	_	15°
Mold Draft Angle Bottom	β	5°	_	15°

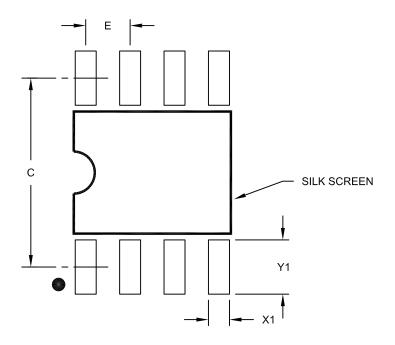
Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. § Significant Characteristic.
- 3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15 mm per side.
- 4. Dimensioning and tolerancing per ASME Y14.5M.
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.
 - REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-057B

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	Units		MILLIMETER		
Dimension	Dimension Limits		MIN NOM		
Contact Pitch	E		1.27 BSC		
Contact Pad Spacing	С		5.40		
Contact Pad Width (X8)	X1			0.60	
Contact Pad Length (X8)	Y1			1.55	

Notes:

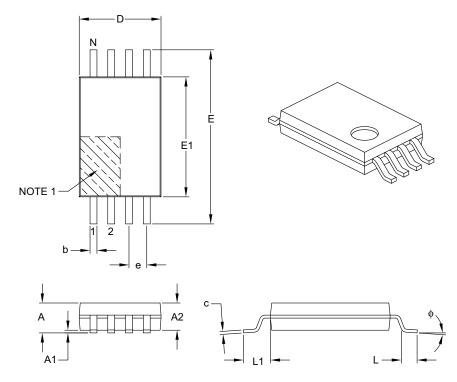
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2057A

8-Lead Plastic Thin Shrink Small Outline (ST) – 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units			MILLIMETERS			
Dimension	Dimension Limits		NOM	MAX			
Number of Pins	N		8				
Pitch	е		0.65 BSC				
Overall Height	Α	_	_	1.20			
Molded Package Thickness	A2	0.80	1.00	1.05			
Standoff	A1	0.05	_	0.15			
Overall Width	Е	6.40 BSC					
Molded Package Width	E1	4.30	4.40	4.50			
Molded Package Length	D	2.90	3.00	3.10			
Foot Length	L	0.45	0.60	0.75			
Footprint	L1	1.00 REF					
Foot Angle	ф	0°	_	8°			
Lead Thickness	С	0.09	_	0.20			
Lead Width	b	0.19	_	0.30			

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15 mm per side.
- 3. Dimensioning and tolerancing per ASME Y14.5M.
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.
 - REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-086B

APPENDIX A: REVISION HISTORY

Revision D (October 2008)

The following is the list of modifications:

1. Updates to packaging outline drawings.

Revision C (January 2007)

The following is the list of modifications:

1. Updates to packaging outline drawings.

Revision B (August 2001)

The following is the list of modifications:

1. Undocumented changes.

Revision A (February 2000)

· Initial release of this document.

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

<u>P4</u>	ART NO. X /XX	Ex	amples:	
	Device Temperature Package Range	a)	MCP3002-I/P:	Industrial Temperature, 8LD PDIP package.
		b)	MCP3002-I/SN:	Industrial Temperature, 8LD SOIC package.
Device	MCP3002: 10-Bit Serial A/D Converter MCP3002T: 10-Bit Serial A/D Converter	c)	MCP3002-I/ST:	Industrial Temperature, 8LD TSSOP package.
	(Tape and Reel) (SOIC and TSSOP only	d)	MCP3002-I/MS:	Industrial Temperature, 8LD MSOP package.
Temperature Range	I = -40 °C to $+85$ °C (Industrial)			
Package	MS = Plastic Micro Small Outline (MSOP), 8-lead P = Plastic DIP (300 mil Body), 8-lead			
	SN = Plastic SOIC (150 mil Body), 8-lead			
	ST = Plastic TSSOP (4.4 mm), 8-lead			

NOTES:

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01/02/08